





Texas INSTRUMENTS

SN54ACT245, SN74ACT245 SCAS452H - SEPTEMBER 1994 - REVISED APRIL 2024

## SNx4ACT245 Octal Bus Transceivers With 3-State Outputs

### **1** Features

- $V_{CC}$  operation of 4.5V to 5.5V
- Inputs accept voltages to 5.5V
- Max t<sub>pd</sub> of 8ns at 5V
- Inputs are TTL-voltage compatible

## 2 Applications

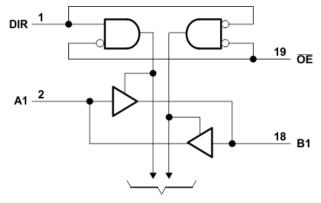
- Pro Audio
- Video and Signage
- Appliances
- Factory Automation and Control

### **3 Description**

The 'AC245 octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

Device Information							
PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>	BODY SIZE <sup>(3)</sup>				
	DB (SSOP, 20)	7.2mm × 7.8mm	7.2mm × 5.3mm				
	DGS (VSSOP, 20)	5.1mm × 4.9mm	5.1mm × 3mm				
	DW (SOIC, 20)	12.8mm × 10.3mm	12.8mm × 7.5mm				
SNx4ACT245	N (PDIP, 20)	24.33mm × 9.4mm	24.33mm × 6.35mm				
	NS (SO, 20)	12.6mm × 7.8mm	12.6mm × 5.3mm				
	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm				
	RKS (VQFN, 20)	4.5mm × 2.5mm	4.5mm × 2.5mm				

- For more information, see Section 11. (1)
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3)The body size (length × width) is a nominal value and does not include pins.



To Seven Other Channels Logic Diagram (Positive Logic)





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## **4** Pin Configuration and Functions

V<sub>CC</sub> DIR 20 19 0E A1 [ 2 A2 🛙 3 18 B1 A3 4 17 п B2 A4 5 16 В3 A5 🛛 6 15 B4 A6 [ 7 14 Β5 A7 [ 8 13 B6 A8 [ 9 12 B7 10 11 B8 GND

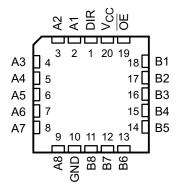


Figure 4-2. SN54ACT245 FK Package Top View



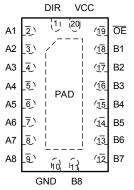


Figure 4-3. SN54ACT245 RKS Package Top View



#### **Pin Functions**

	PIN	TYPE <sup>1</sup>	DESCRIPTION
NO.	NAME		DESCRIPTION
1	DIR	I/O	Direction Pin
2	A1	I/O	A1 Input/Output
3	A2	I/O	A2 Input/Output
4	A3	I/O	A3 Input/Output
5	A4	I/O	A4 Input/Output
6	A5	I/O	A5 Input/Output
7	A6	I/O	A6 Input/Output
8	A7	I/O	A7 Input/Output
9	A8	I/O	A8 Input/Output
10	GND	_	Ground Pin
11	B8	I/O	B8 Input/Output
12	B7	I/O	B7 Input/Output
13	B6	I/O	B6 Input/Output
14	B5	I/O	B5 Input/Output
15	B4	I/O	B4 Input/Output
16	B3	I/O	B3 Input/Output
17	B2	I/O	B2 Input/Output
18	B1	I/O	B1 Input/Output
19	OE	I/O	Output Enable
20	VCC	_	Power Pin

(1) Signal Types: I = Input, O = Output, I/O = Input or Output



### **5** Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	-0.5	7	V	
VI	Input voltage <sup>(1)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
Vo	Output voltage <sup>(1)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	$V_{I} < 0 \text{ or } V_{I} > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current	$V_{O}$ < 0 or $V_{O}$ > $V_{CC}$		±20	mA
lo	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±50	mA
	Continuous current through $V_{CC}$ or GND		±200	mA	
T <sub>stg</sub>	stg Storage temperature range			150	°C

(1) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### 5.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±3000	
V <sub>(ES</sub>	SD) Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 $^{(2)}$	±1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

#### **5.3 Recommended Operating Conditions**

		SN54AC	CT245	SN74A	UNIT	
		MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5.5	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
Vo	Output voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		-24		-24	mA
I <sub>OL</sub>	Low-level output current		24		24	mA
Δt/Δv	Input transition rise or fall rate		8		8	ns/V
Τ <sub>Α</sub>	Operating free-air temperature	-55	125	-40	85	°C

### **5.4 Thermal Information**

			SNx4ACT245							
THERMAL METRIC <sup>(1)</sup>		DB (SSOP)	DGS (VSSOP)	DW (SOIC)	N (PDIP)	NS (SOP)	PW (TSSOP)	RKS (VQFN)	UNIT	
				20 P	INS					
R <sub>θJA</sub>	R <sub>0JA</sub> Junction-to-ambient thermal resistance		123.5	98.6	69	99.7	126.6	67.7	°C/W	

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

### **5.5 Electrical Characteristics**

DAI		TEST CONDITIONS	V	т	<sub>A</sub> = 25°C		SN54AC	T245	SN74ACT245		UNIT
PARAMETER		TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		L _ 50.04	4.5 V	4.4	4.49		4.4		4.4		
		I <sub>OH</sub> = –50 μA	5.5 V	5.4	5.49		5.4		5.4		
V		L = 24 mA	4.5 V	3.88			3.7		3.76		V
V <sub>OH</sub>		I <sub>OH</sub> = -24 mA	5.5 V	4.86			4.7		4.76		v
		I <sub>OH</sub> = -50 mA <sup>(1)</sup>	5.5 V				3.85				
		I <sub>OH</sub> = -75 mA <sup>(1)</sup>	5.5 V						3.85		
		L = 50 uA	4.5 V		0.001	0.1		0.1		0.1	
		I <sub>OL</sub> = 50 μA	5.5 V		0.001	0.1		0.1		0.1	
V		L = 24 mA	4.5 V			0.36		0.5		0.44	V
V <sub>OL</sub>		I <sub>OL</sub> = 24 mA	5.5 V			0.36		0.5		0.44	v
		I <sub>OL</sub> = 50 mA <sup>(1)</sup>	5.5 V					1.65			
		I <sub>OL</sub> = 75 mA <sup>(1)</sup>	5.5 V							1.65	
I <sub>OZ</sub>	A or B ports <sup>(2)</sup>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V			±0.5		±10		±5	μA
l <sub>l</sub>	OE or DIR	$V_{I} = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μA
I <sub>CC</sub>		$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	5.5 V			4		80		40	μA
ΔI <sub>CC</sub> <sup>(3)</sup>		One input at 3.4 V, Other inputs at GND or $V_{CC}$	5.5 V		0.6			1.6		1.5	mA
Ci		V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		4.5						pF
Cio		V <sub>O</sub> = V <sub>CC</sub> or GND	5 V		15						pF

over recommended operating free-air temperature range (unless otherwise noted)

(1) Not more than one output should be tested at a time, and the duration of the test should not exceed 2 ms.

(2) For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.

(3) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.

### **5.6 Switching Characteristics**

over recommended operating free-air temperature range, V<sub>CC</sub> = 5 V ± 0.5 V (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM	ROM TO		₄ = 25°C		SN54AC	T245	SN74AC	T245	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	A or B	A or B B or A —	1	4	7.5	1	9	1.5	8	ns
t <sub>PHL</sub>	AUD		1	4	8	1	10	1	9	115
t <sub>PZH</sub>	OE	A or B	1	5	10	1	12	1.5	11	20
t <sub>PZL</sub>	UE	AUB	1	5.5	10	1	13	1.5	12	ns
t <sub>PHZ</sub>	OE	A or B	1	5.5	10	1	12	1	11	20
t <sub>PLZ</sub>		AUB	1	5	10	1	12	1.5	11	ns

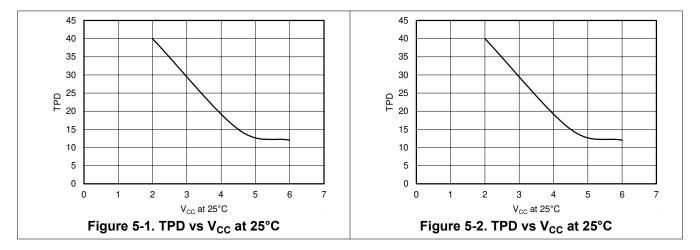
### **5.7 Operating Characteristics**

 $V_{CC} = 5 V, T_A = 25^{\circ}C$ 

	PARAMETER	TEST C	TYP	UNIT	
C <sub>pd</sub>	Power dissipation capacitance	C <sub>L</sub> = 50 pF,	f = 1 MHz	45	pF

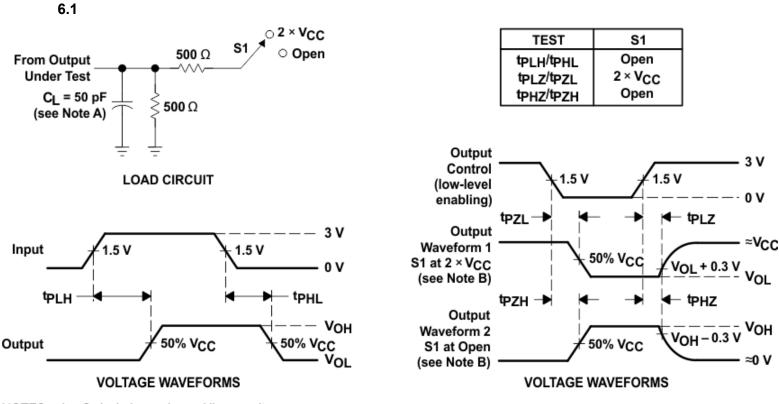


### **5.8 Typical Characteristics**





### 6 Parameter Measurement Information



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$  t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

### Figure 6-1. Load Circuit and Voltage Waveforms



### 7 Detailed Description

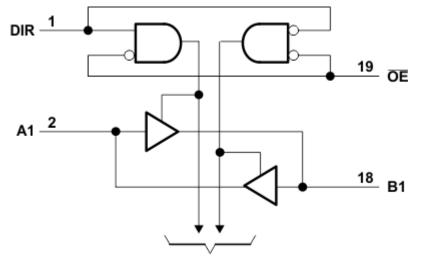
### 7.1 Overview

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

When the output-enable ( $\overline{OE}$ ) is low, the device passes noninverted data from the A bus to the B bus or from the B bus to the A bus, depending upon the logic level at the direction-control (DIR) input. A high on  $\overline{OE}$  disables the device so that the buses are effectively isolated.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### 7.2 Functional Block Diagram



To Seven Other Channels Logic Diagram (Positive Logic)

#### 7.3 Feature Description

The SNx4ACT245 devices have a wide operating  $V_{CC}$  range from 4.5 V to 5.5 V with slower edge rates to minimize output ringing.

#### 7.4 Device Functional Modes

Section 7.4 lists the function modes of the SNx4ACT245.

Tab	Table 7-1. Function Table					
IN	PU	TS <sup>(1)</sup>	OPERATION			
OE		DIR	OPERATION			
L		L	B data to A bus			
L		Н	A data to B bus			
Н		Х	Isolation			

 H = High Voltage Level, L = Low Voltage Level, X = Don't Care



### **8 Application Information Disclaimer**

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The SNx4ACT245 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs.

#### 8.2 Typical Application

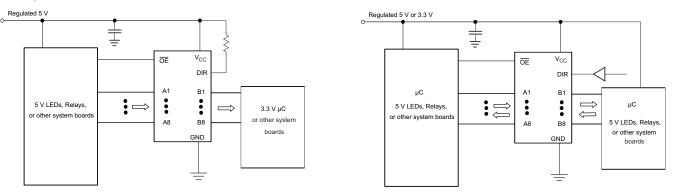


Figure 8-1. Typical Application Schematic

#### 8.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

#### 8.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
  - For rise time and fall time specifications, see  $\Delta t/\Delta V$  in the Section 5.3 table.
  - For specified High and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in the Section 5.3 table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid  $V_{CC}$ .
- 2. Recommend Output Conditions
  - Load currents should not exceed 35 mA per output and 70 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.



#### 8.2.3 Application Curve

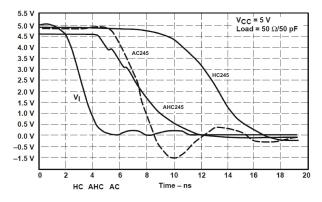


Figure 8-2. Switching Characteristics Comparison

#### 8.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Section* 5.3.

Each V<sub>CC</sub> pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$ F is recommended; if there are multiple V<sub>CC</sub> pins, then 0.01  $\mu$ F or 0.022  $\mu$ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu$ F and a 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

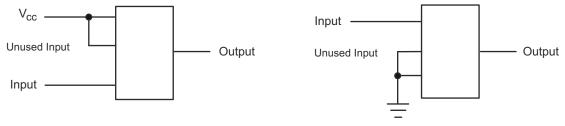
#### 8.4 Layout

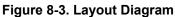
#### 8.4.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Section 8.4.2 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the IOs, so they cannot float when disabled.

#### 8.4.2 Layout Example







### 9 Device and Documentation Support

#### 9.1 Documentation Support

#### 9.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY		
SN54ACT245	Click here	Click here	Click here	Click here	Click here		
SN74ACT245	Click here	Click here	Click here	Click here	Click here		

#### Table 9-1. Related Links

#### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 9.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 9.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.



### **10 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	Changes from Revision G (March 2024) to Revision H (April 2024) Pag								
•	Updated R0JA values: DB = 70 to 105.4, DW = 58 to 98.6, NS = 60 to 99.7, PW = 83 to 126.6, all value	es in							
	°C/W	5							

CI	nanges from Revision F (January 2023) to Revision G (March 2024)	Page
•	Added DGS and RKS packages to Device Information table, Pin Configuration and Functions section an	nd
	Thermal Information table	1
•	Changed Package Information to Device Information and added package size to table	1

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8766301M2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 8766301M2A SNJ54 ACT245FK	Samples
5962-8766301MRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8766301MR A SNJ54ACT245J	Samples
5962-8766301MSA	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8766301MS A SNJ54ACT245W	Samples
SN74ACT245DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AD245	Samples
SN74ACT245DGSR	ACTIVE	VSSOP	DGS	20	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT245	Samples
SN74ACT245DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	ACT245	
SN74ACT245DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT245	Samples
SN74ACT245DWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT245	Samples
SN74ACT245DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT245	Samples
SN74ACT245N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74ACT245N	Samples
SN74ACT245NE4	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74ACT245N	Samples
SN74ACT245NS	ACTIVE	SO	NS	20		TBD	Call TI	Call TI	-40 to 85	ACT245	Samples
SN74ACT245NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT245	Samples
SN74ACT245PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	AD245	
SN74ACT245PWG4	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85		
SN74ACT245PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AD245	Samples
SN74ACT245PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AD245	Samples
SN74ACT245RKSR	ACTIVE	VQFN	RKS	20	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT245	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54ACT245FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 8766301M2A SNJ54 ACT245FK	Samples
SNJ54ACT245J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8766301MR A SNJ54ACT245J	Samples
SNJ54ACT245W	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8766301MS A SNJ54ACT245W	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE OPTION ADDENDUM

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#### OTHER QUALIFIED VERSIONS OF SN54ACT245, SN74ACT245 :

- Catalog : SN74ACT245
- Automotive : SN74ACT245-Q1, SN74ACT245-Q1
- Military : SN54ACT245
- Space : SN54ACT245-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



Texas

STRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ACT245DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74ACT245DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74ACT245DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74ACT245NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74ACT245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74ACT245RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1



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## PACKAGE MATERIALS INFORMATION

9-Apr-2024



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ACT245DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74ACT245DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74ACT245DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ACT245NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74ACT245PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74ACT245RKSR	VQFN	RKS	20	3000	210.0	185.0	35.0

### TEXAS INSTRUMENTS

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### TUBE



## - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-8766301M2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-8766301MSA	W	CFP	20	25	506.98	26.16	6220	NA
SN74ACT245N	N	PDIP	20	20	506	13.97	11230	4.32
SN74ACT245NE4	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54ACT245FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54ACT245W	W	CFP	20	25	506.98	26.16	6220	NA

# **DB0020A**



# **PACKAGE OUTLINE**

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



# DB0020A

# **EXAMPLE BOARD LAYOUT**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DB0020A

# **EXAMPLE STENCIL DESIGN**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **RKS 20**

2.5 x 4.5, 0.5 mm pitch

# **GENERIC PACKAGE VIEW**

### VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





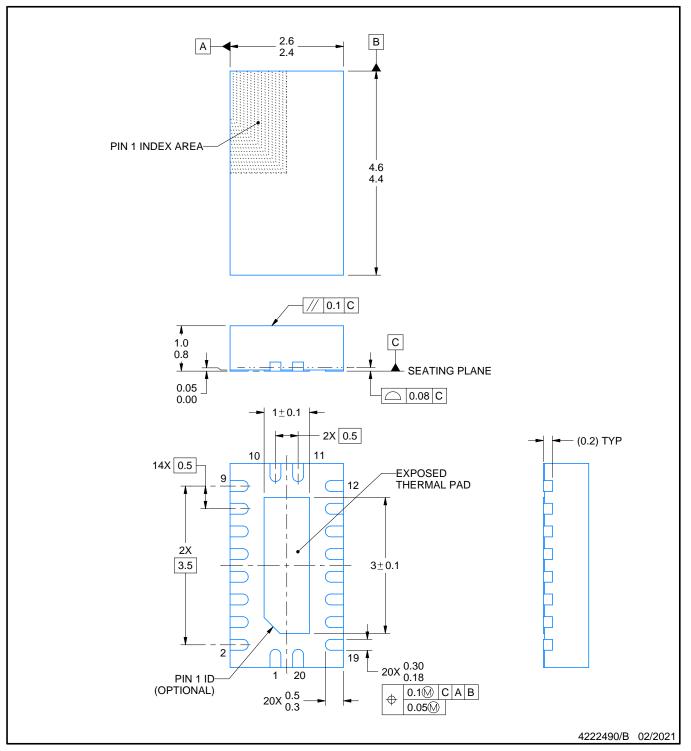
# **RKS0020A**



# **PACKAGE OUTLINE**

## VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

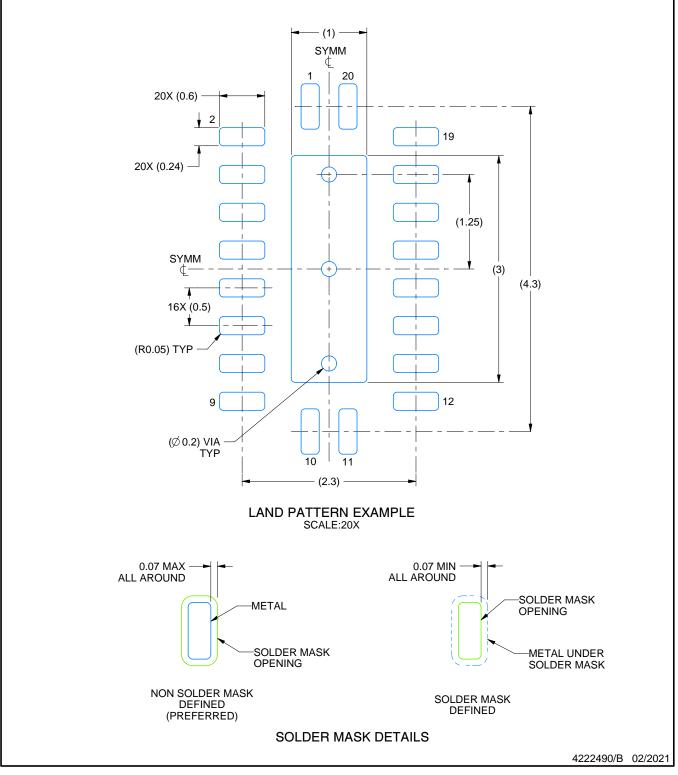


# **RKS0020A**

# **EXAMPLE BOARD LAYOUT**

## VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

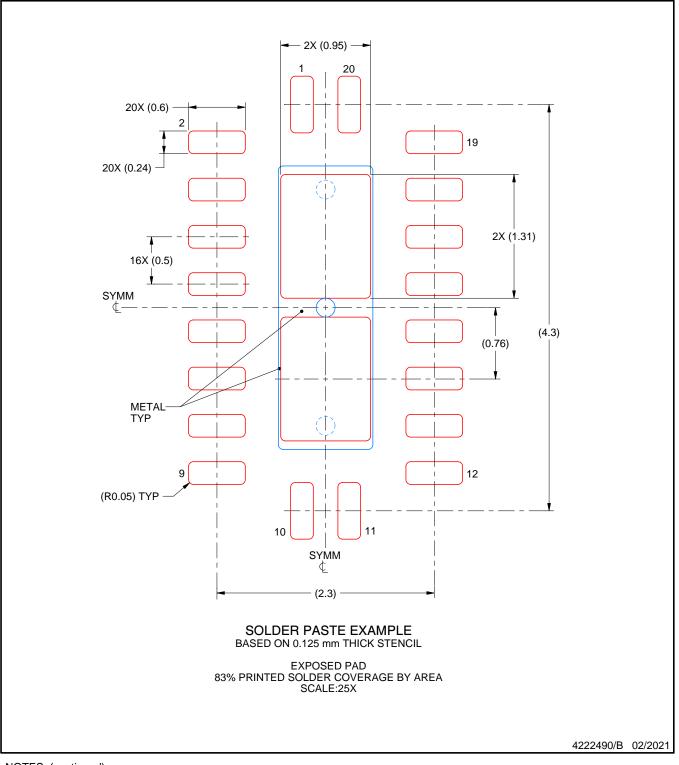


# **RKS0020A**

# **EXAMPLE STENCIL DESIGN**

## VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



### MECHANICAL DATA

### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## FK 20

### 8.89 x 8.89, 1.27 mm pitch

## **GENERIC PACKAGE VIEW**

## LCCC - 2.03 mm max height

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





## N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



# **DW0020A**



## **PACKAGE OUTLINE**

### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



# DW0020A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DW0020A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice. В.
  - C. This package can be hermetically sealed with a ceramic lid using glass frit.
    D. Index point is provided on cap for terminal identification only.
    E. Falls within Mil-Std 1835 GDFP2-F20



# **PW0020A**



## **PACKAGE OUTLINE**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



## PW0020A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## PW0020A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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